

# Two Approaches to the Studying of a Hall Thruster Discharge Chamber Erosion Process

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**Abstract:** The problem of Hall thruster (HT) discharge chamber (DC) ion sputtering that restricts HT life-time is analyzed. Two approaches to study regularities of an ion flow to the DC wall that lead to destruction of DC are studied. According to the first approach ions directed to walls mainly owing to radial component of the electric field in all DC space. According to second idea DC sputtering by ions moving to DC surface owing to its chaotic velocity. Near to DC surface ions are accelerated owing to close to the wall potential drop. To calculate flow of ions sputtering DC surface the radial component of electric field was set of various values. Operational characteristics of HT schema like model M-70 (worked out by design bureau “Fakel” in former USSR) was used to test result of erosion processes mathematical modeling and in further to estimate life-time of HT M-40 type designed in Ukraine in National State University in Dnepropetrovsk. Researches include the following interconnected parts. 1. Calculation of potential distribution between the anode and cathode of HT including two intervals: in the DC and outside it base on hydrodynamic 1D model. 2. Calculation of potential drop in close to the wall layer, including discussion of a problem of limiting electron temperature in ceramic DC. 3. 2D modeling of an ion origin process in DC base on Monte-Carlo method. 4. Modeling of ion movement in DC and DC wall erosion process.

## Nomenclature

$B$	=	magnetic field induction
$I_{e0}$	=	electron current from the cathode to the discharge chamber
$I_d$	=	discharge current
$h_c$	=	height of cycloid
$n_{pl}$	=	plasma concentration
$n_h$	=	concentration of charges in the field of plasma heterogeneity
$S$	=	square of cross-section of discharge chamber, square of discharge chamber segment surface
$T_e$	=	electron temperature
$T_s$	=	discharge chamber surface temperature
$V_y, V_r, V_x$	=	components of electron velocity

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- $U_c$  = cathode potential drop  
 $U_d$  = discharge voltage  
 $\Delta\varphi_h$  = potential drop because of plasma polarization in the field of charges heterogeneity

## I. Introduction

BASIC HT circuit has been created more than 50 years ago and due to a good combination of operational characteristics of the first models (high operational efficiency, high reliability) HT is exploited already tens years. For further HT modernization it is necessary to increase HT life-time by effecting to discharge chamber erosion processes. A base for this purpose is the understanding of a role of the basic processes (factors), which influence DC erosion. These are the following. 1. Distribution of electric potential and corresponding values of radial and axial a component of an electric field. 2. Formation of close to the wall potential drop. 3. Distribution of concentration and temperature of electrons. 4. Distribution of ion origins intensity in DC.

*In the second section* of paper the distribution of a discharge potential along an axis was determined on the basis of hydrodynamic 1D model on two sites: in DC in a zone of ionization and outside DC up to the cathode-neutralizer (CN). We offer the equation, which should be used for potential distribution determining in a radial direction of DC. However we are not ready to offer full model for the decision of this separate task. By numerical calculations we have varied a radial component of an electric field so that results of calculations obviously did not contradict known results of experiments. *In the third section* we determine the value of close to the wall potential drop and we try to overcome the contradiction between known data of experiments that the electron temperature in DC can surpass 40 eV and the assumption that because of effect of secondary electronic emission from DC surface the electron temperature cannot surpass a limit in 30 eV. *In the fourth section* we yield results of Monte-Carlo modeling of plasma parameters distribution in DC - average energy and concentration of electrons, intensity of ion origin process (quantity of ions born per second per unit of volume). *In the fifth section* we yield results of calculation of DC destruction within 1000 hours as test calculation for HT M-70 type.

Using the developed techniques of an estimation of DC erosion, it is planned to predict resource of HT M-40, developed in Ukraine in Dnipropetrovs'k National State University.

## II. Features of HT plasma processes 1D hydrodynamic modeling

The basic applicability 1D hydrodynamic model consist in determining of potential drop on two sites of a discharge interval: first - from the cathode-neutralizer (CN) up to DC edge - a zone of acceleration of ions (ZA) with potential drop  $U_{za}$ ; second - from DC edge up to section inside DC, in which the potential reaches a maximum - a zone of ionization of gas (ZI) with potential drop  $U_{zi}$  (Fig. 1a). Features of model consist that the following balance equations are written for two major sites - ZI and the ZA, and also for their border.

To determine of an electron stream in DC probably to use some approaches. One of them is the following.

By development of model it was assumed that electrons emitted by CN and that reached DC, passing area ZA (Fig. 1a) mainly due to distortion of close azimuthal drift - being displaced at each collision (with atoms, ions, in local plasma fluctuations, on ion beam boundary) to DC edge on size  $h_c=2\cdot R_l$  (height of a cycloid equal to twice Larmor radius). Should occur at least  $N_{min}$  collisions that electron has reached DC edge. Probably to look electron movement from the cathode to DC as likelihood process, believing that probability of electron displacement to DC on size of a cycloid after one collision -  $P_c$ . Then the resulted probability  $P$ , that electron emitted by the cathode have reached DC

$$P=(P_c)^{N_{min}}, \quad (1)$$

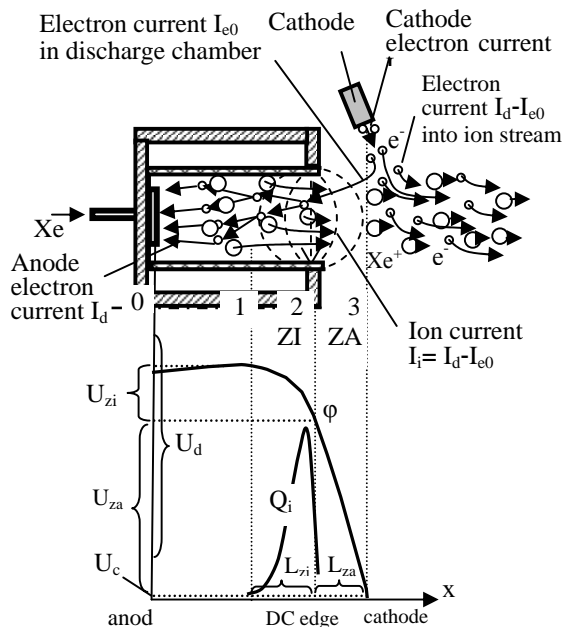


Figure 1a. Electron currents distribution. Potential  $\varphi$  and ion origin intensity  $Q_i$  distributions in the HT discharge interval.

where:  $P_c=f(\varepsilon_e)$  - probability that electron ( $\varepsilon_e$  - energy) was displaced on a height of a cycloid  $h_c=2 \cdot R_1$  to DC edge due to any collision;  $N_{\min}$  - a minimum quantity of electron-atom collisions, necessary to reach DC at the  $L_{za}$  distance from cathode

$$N_{\min} = \int_3^2 \frac{dx}{h_c} \quad (2)$$

Allocating among all electron flow  $I_d/e$  ( $I_d$  - electrons emitted by the cathode is total discharge current) part  $I_{e0}/e$  - electrons reached DC, a ratio of these flows is determined as

$$I_{e0}=I_d \cdot (P_c)^{N_{\min}} \quad (3)$$

Other approach to determine electron stream in DC is the following. It is supposed, that carry of electrons across a magnetic field occurs because of dispersion of electrons on plasma heterogeneities, extended in an axial direction (see a Fig. 1b). These heterogeneities of plasma arise in a zone of ionization in DC because of heterogeneity of gas concentration in DC  $\Delta n_a$ , so  $\Delta n_a/n_a \approx 0.01$ . The value if heterogeneity of gas concentration is determined by non-uniformity of distribution of gas in DC through apertures in the anode-gas distributor (nearly 5 ... 10 mm that corresponds to distance between apertures in the anode). After ionization of gas, in which there are heterogeneity, in plasma arise heterogeneity of charge concentration  $\Delta n_i$ , so  $\Delta n_i/n_{pi} \approx 0.01$ . Extent of these areas of heterogeneity of charges concentration is determined by Debye screening distance  $r_D \sim (T_e/n_i)^{1/2}$ . At that there is an ionization of gas in the field of heterogeneity, and in same time, the ions born in DC, are accelerated and leave DC. Therefore heterogeneity in a stream of plasma are kept in the form of extended along an axis tubes with the increased concentration of plasma until atoms "burn out" in a zone of heterogeneity of gas in DC. Owing to electron drift in an azimuthal direction outside of DC there is magnetized electrons, there is a polarization of charges in the field of local heterogeneity of plasma and there is a local azimuthal electric field. Under influence of it close drift of electrons can be braked. "Slow" electrons can be displaced in a direction to DC creating an axial current from the cathode in DC.

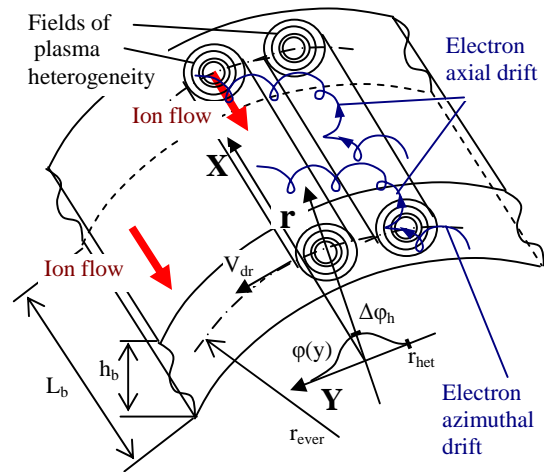


Figure 1b. Axial electron drift because of dispersion of "slow" electrons on plasma heterogeneities in a stream of ions.

Potential drop in the field of heterogeneity can be estimated from the equation, taking that azimuthal electron flow retard due to potential drop  $\Delta\phi_h$  appeared because of plasma polarization in the field of charges heterogeneity (look in Fig. 1b)

$$\frac{n_{pl}}{n_h} = \int_{\sqrt{\Delta\phi_h \cdot q \cdot 2/m}}^{\infty} \frac{V_y - \sqrt{\Delta\phi_h \cdot 2 \cdot q/m}}{V_y} \cdot f(v_x, v_y, v_r, T_e) / n_{pl} \cdot dv_y \cdot \int_{\frac{r_h \cdot v_y}{2 \cdot 6 \cdot R_1}}^{\frac{r_h \cdot v_y}{2 \cdot 6 \cdot R_1}} dv_r \cdot \int_{-\infty}^{\infty} dv_x$$

where:  $n_{pl}$  - plasma concentration;  $n_h$  - concentration of charges in the field of plasma heterogeneity, can be estimated on heterogeneities of atoms;  $\Delta\phi_h$  - potential drop because of plasma polarization in the field of charges heterogeneity;  $R_1$  - Larmor electron radius;  $r_h$  - the value of plasma heterogeneity, a boundary condition for  $V_r$  that allocates electrons, which cannot flow round heterogeneity of plasma;  $f(v_x, v_y, v_r, T_e)$  - density of function of electron distribution on velocities in plasma of ion flow.

Electron current  $I_{e0}$  in an axial direction across a magnetic field because of electron dispersion on plasma heterogeneities, under the order of electron stream from the cathode in DC, can be estimated as

$$I_{e0} = r_{ever} \cdot \pi \cdot h_b \cdot q \cdot \int_0^{\sqrt{\Delta\phi_h \cdot q \cdot 2/m}} v_y / 2 \cdot f(v_x, v_y, v_r, T_e) \cdot dv_y \cdot \int_{\frac{h_b \cdot v_y}{2 \cdot 6 \cdot R_1}}^{\frac{h_b \cdot v_y}{2 \cdot 6 \cdot R_1}} dv_r \cdot \int_{-\infty}^{\infty} dv_x \cdot \left( \frac{2 \cdot \pi \cdot r_{ever} \cdot h_b}{r_h \cdot r_h} \right),$$

where:  $h_b$  - width of ion stream,  $q$  - electron charge,  $r_{ever}$  - average radius of ion stream.

Current  $I_{e0}$  exists owing to electrons, which have not overcome retarding potential  $\Delta\phi_h$ .

For calculations we used the first approach described above. However, neither first, nor second approaches do not solve all the questions connected with electron maxwellisation and specific influence of a magnetic field on HT discharge current.

*Equation of energy flow in zones ZA and ZI of discharge interval.*

Electron temperature  $T_e(x)$  on distance  $x$  from DC edge was determined by balance

$$d(q_e(x) \cdot 5/2 \cdot e \cdot T_e(x)) / dx = q_e(x) \cdot e \cdot E(x) - Q_{wall}(x) - Q_{ion}(x), \quad (4)$$

where:  $q_e(x) = V_{eX}(x) \cdot n_e(x)$  - electron flow, collected by electrons in an electric field  $E$ ,  $V_{eX}$  - axial electron velocities,  $n_e$  - electron concentration;

$$Q_{wall}(x) = 2 \cdot T_e \cdot e \cdot \sqrt{\frac{T_e \cdot e}{2 \cdot \pi \cdot m}} \cdot \exp(-\phi_w / T_e) \cdot \frac{2 \cdot \delta}{(r_{out} - r_{in})^2} - \text{energy flow to the DC wall, } \delta - \text{width of the layer ion flow}$$

to the DC wall mainly come from,  $r_{out}$  - radius of the DC outer wall,  $r_{in}$  - radius of the inner wall;

$Q_{ion}(x) = q_e(x) \cdot \phi_i \cdot e \cdot \sigma_i \cdot n_a(x) \cdot V_e(x) / V_{eX}(x)$  - energy flow spent for atom ionization,  $V_e = \sqrt{3 \cdot e \cdot T_e(x) / m}$  - full electron velocity,  $\sigma_i$  - ionization cross section,  $\phi_i$  - ionization potential of atom,  $n_a$  - atom concentration.

*Equation of electron and ion velocities in cross-section 2.*

Axial electron velocity  $V_{eX2}$  in cross-section 2 at the DC edge, in view of: full electron velocity  $V_{e2}$ , total collision cross-section  $\sigma_\Sigma$ , atom concentration  $n_{a2}$  taking into account cathode  $\dot{m}_c$  and anode  $\dot{m}_a$  mass flow rates was determined as

$$V_{eX2} = V_{e2} \cdot \sigma_\Sigma \cdot n_{a2} \cdot h_{c2} \cdot P_c. \quad (5)$$

Full electron velocity  $V_{e2}$  at the DC edge is determined by the electron kinetic energy, taking into account, that electrons reach DC mainly due to elastic collisions

$$V_{e2} = \sqrt{3 \cdot e \cdot T_e / m}. \quad (6)$$

*Equation for discharge current determining.*

The anode discharge current  $I_d$  is determined by the current  $I_{e0}$  avalanchely increased in ZI from section 1 to 2 so, that

$$I_d = I_{e0} \cdot Z, \quad \text{where value } Z = \exp\left(\int \alpha(x) \cdot dx\right) \quad (7)$$

where:  $\alpha(x)$  - number of ionization collisions per unit of length of electron run along axis  $X$

$$\alpha(x) = n_a(x) \cdot \sigma_i \cdot \frac{V_e(x)}{V_{eX}(x)}. \quad (8)$$

*Equation for determining of atom concentration decreasing in zone ZI because of ionization.*

Concentration  $n_a(x)$  in any section on distance  $x$  from section 2 was calculated as

$$n_a(x) = \frac{\dot{m}_a}{M \cdot V_a(x) \cdot S} - \frac{I_d - I_{e0} \cdot \exp\left(\int_0^x \alpha(x) \cdot dx\right)}{M \cdot V_a(x) \cdot S \cdot e}, \quad (9)$$

taking into account:

"burning out" of atoms in DC ionization process, anode mass flow rate  $\dot{m}_a$  and that  $\dot{m}_a/M/S$  - atom flow through the DC area of cross-section S with axial atom velocity  $V_a$ ;

$$I_d - I_{e0} \cdot \exp\left(\int_0^x \alpha(x) \cdot dx\right) - \text{ion flow in section } x.$$

*Equation for electron and ion concentration determining in cross-section 2.*

Ion -  $n_{i2}$  and electron -  $n_{e2}$  concentrations are equal and were determined at the DC edge as

$$n_{i2} = \frac{I_i}{V_{i2} \cdot e \cdot S} = \frac{I_{e0} \cdot (X-1)}{V_{i2} \cdot e \cdot S} = n_{e2} = \frac{I_{e0}}{V_{eX2} \cdot e \cdot S}. \quad (10)$$

where  $V_{i2}$  - ion velocity at DC edge is determined roughly by  $U_{zi}/2$  - the average potential drop in ZI ion accelerated due to

$$V_{i2} = \sqrt{e \cdot U_{zi} / M}. \quad (11)$$

*Equation of potential drop balance in discharge interval.*

Balance of the HT discharge voltage is calculated on equation

$$U_d = U_c + U_{za} + U_{zi}. \quad (12)$$

Processes in the cathode were not studied separately and cathode potential drop  $U_c$  was set to follow typical experimental dependence on discharge current  $I_d$ , adjusting constants a and b

$$U_c = a + (I_d - b)^2. \quad (13)$$

The following boundary conditions were taken. We suppose that back potential drop on a site (01) much less when potential drop in ZI. The HT magnetic system is included in a discharge circuit, but we neglect potential drop

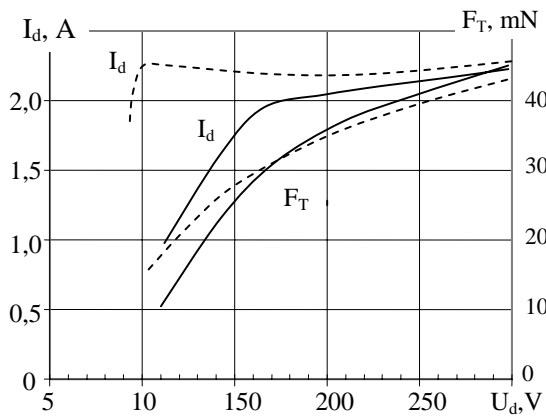


Figure 2a. HT M-70 type V-I characteristic and thrust  $F_T$  in the stationary mode.

— Calculated on hydrodynamic model  
 - - - - - Experimental measurements

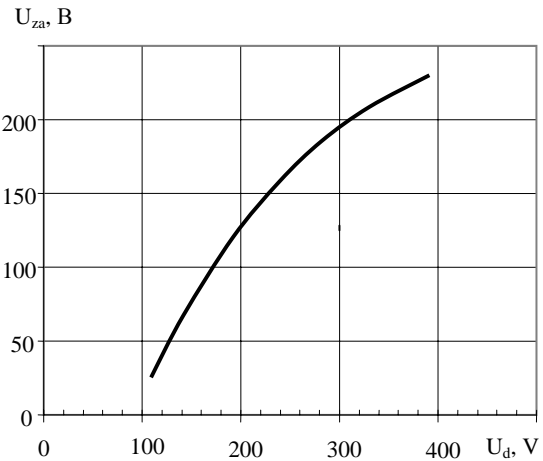


Figure 2b. Potential drop  $U_{za}$  in zone DC edge - cathode-neutralizer at various discharge voltage  $U_d$ , calculated for HT M-70 type.

on magnetic coils. We believe, that ions and electrons will be neutralized on DC walls and thus the stream of electron on DC wall is determined by the retarding potential at a wall of value  $\Delta\phi_w=2.5T_e$ .

Forms of the curves of magnetic and electric field distribution are typical for wide range of discharge voltage. These curves were taken from the experimental researches, but the value of potential drop was calculated.

Volt-ampere characteristic of HT was determined by calculation of Eqs. (1 – 13). As a test, HT integral characteristics (Fig. 2) of model M-70 have been calculated in a nominal discharge mode: Xe mass flow rate through cathode-neutralizer – 0.3 mg/s; through the anode gas-distributor – 2.5 mg/s. Cathode-neutralizer is located on the distance of 7 mm from a DC edge. Magnetic coils are included in a discharge circuit. The deviation of calculated and experimental data dependences of a discharge current (Fig. 2a) reflect inexact determination of the mechanism of electron conductivity in a interval cathode-neutralizer – DC edge. Potential drop  $U_{za}$  on site of acceleration (from edge DC – up to cathode) is shown in Fig. 2b.

### III. Electron distribution along a magnetic field force line

It is known that distribution of an electric field is described by Poisson equation, which, however, is difficult to use directly for HT plasma when plasma concentration is  $10^{17} \dots 10^{18} \text{ m}^{-3}$ . So-called equation of “thermolized potential”, offered by A. Morozov is usually used

$$\phi_\gamma = \phi_\gamma^0 + T_e \cdot \ln(n_\gamma/n_\gamma^0),$$

where  $\phi_\gamma$  - potential in a running point on force line  $\gamma$ ,  $\phi_\gamma^0$  - potential in a point on an average line of DC on magnetic field B force line  $\gamma$ ,  $n_\gamma$  – electron concentration with temperature  $T_e$  in a running point on B force line  $\gamma$ ,  $n_\gamma^0$  - concentration электронов in a point on an average line of the channel on B force line  $\gamma$ .

It is necessary that electrons move free along a B force line of magnetic field. However in HT magnetic field distribution is characterized by an essential gradient in a radial direction. Increase of an induction from 15 mTl up to 22 mTl during 1 cm creates known effect of "a magnetic mirror" that is not considered by the equation “thermolized potential”. It, certainly, leads to errors by determining of an HT electric field potential distribution that is corrected by various researchers.

We suggest to consider effect of "a magnetic mirror" as follows. Electron stream электронов  $q_e = \langle v_r \cdot n_e \rangle$  and electron concentration  $n_e$  along a B force line of a magnetic field can be certain, considering that

$$(V_y^2 + V_x^2)/B = \text{const}$$

where  $V_y$  and  $V_x$  - components of electron velocity, perpendicular to a B force line (Fig. 3). Then electron stream from a point, where an induction -  $B_0$  and potential  $\phi_0$  in a point, where an induction B and potential  $\phi$  is determined,

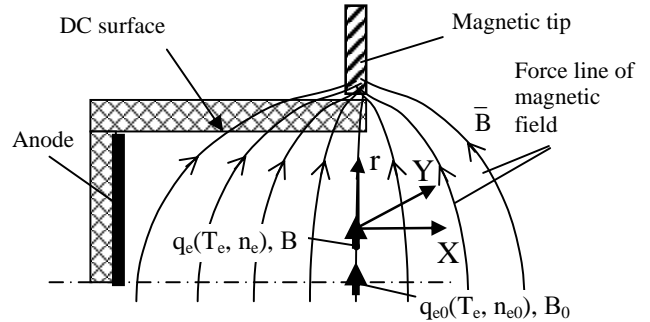


Figure 3. Electron stream  $q_{e0}$  along a force line of a magnetic field.

$$\frac{\int_0^\infty v_r \cdot f(v_x, v_y, v_r, T_e) \cdot dv_r \cdot 2 \cdot \left( \frac{v_r}{\sqrt{B/B_0 - 1}} \right) \int_0^\infty dv_x \cdot 2 \cdot \sqrt{\frac{v_r^2}{B/B_0 - 1} - (v_y^2 + v_x^2)} \int_0^\infty dv_y}{\sqrt{\Delta\phi \cdot q \cdot 2/m}} = \langle v_r \cdot n_e \rangle = q_e$$

where  $v_r$  - a component of electron velocity along a force line of a magnetic field,  $\Delta\phi = \phi_0 - \phi$  – potential drop. It has been calculated numerically  $q_e/q_{e0}$  in some ranges of  $\Delta\phi$ ,  $B/B_0$ ,  $T_e$  and yield are resulted in a Fig. 4, 5.

### IV. Potential drop in close to the wall layer

It is expected<sup>5</sup>, that electron temperature will not surpass 30 eV if DC of HT is made of ceramics. Since temperature becomes more than this limit close to the wall potential drop becomes zero owing to strong secondary electronic emission of DC surface. At this critical value of the SEE coefficient the charge-saturation regime is reached. Data of experiments that electron temperature in DC surpasses 40 eV are known also<sup>3,4</sup>. In our opinion this

contradiction can be solved as follows. We assume that electron distribution function on energy (EDFE) is close to Maxwell, but is not precisely Maxwell. The deviation consists that there is no so-called "tail" with electron of high energy. Probably, that EDFE it would more precisely be described by Druvestain distribution. Now there is no explanation of physical processes, which would confirm the fact of electron Maxwellization in DC of HT for the period of electron movement from a wall to wall of DC. Data about EDFE, received from probe measurements, cannot capture a range of energy more than  $(5...6)T_e$  since in this range the ion current to a probe is close to value of an electron current to a probe.

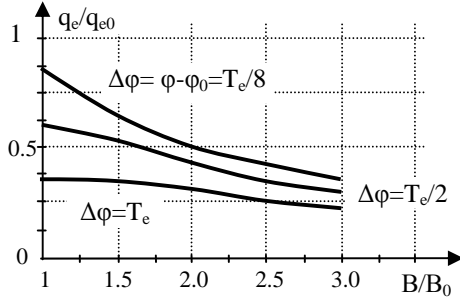


Figure 4. Ratio  $q_e/q_{e0}$  of electron stream moving along a force line of a magnetic field from a point, where an induction -  $B_0$  and potential  $\phi_0$  in a point where an induction  $B$  and potential  $\phi$ , electron temperature  $T_e=40$  eV,  $B_0=15$  mTl.

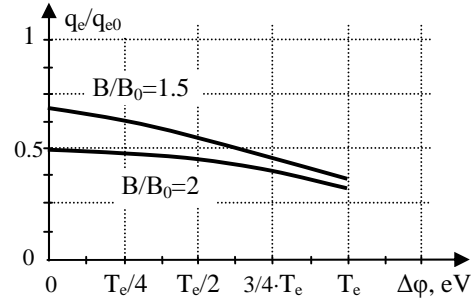


Figure 5. Ratio  $q_e/q_{e0}$  of electron stream moving along a force line of a magnetic field from a point, where an induction -  $B_0$  and potential  $\phi_0$  in a point where an induction  $B$  and potential  $\phi$ , electron temperature  $T_e=40$  eV,  $B_0=15$  mTl.

In our calculations we suppose that electrons with energy more when  $3 \cdot T_e$  are absent in EDFE.

Potential drop  $\Delta\phi_w$  between plasma and DC wall in so-called close to the wall layer in some range of electron temperatures  $T_e$  (Fig. 6) is determined. For this purpose it is suggested the equation of balance of radial streams of ions and electrons to the DC surface, in view of emission properties of the DC surface

$$\int_{\frac{\sqrt{\Delta\phi_w \cdot q \cdot 2/m}}{v_r}}^{v_{lim}} \frac{1 - S(\varepsilon)}{v_r} dv_r \int_{-\infty}^{v_{lim}} dv_x \int_{-\infty}^{v_{lim}} f(v_x, v_y, v_r, T_e) \cdot dv_y = \langle V_{ir} \cdot n_i \rangle$$

where:  $f(v_x, v_y, v_r, T_e) = A \cdot \exp(-\varepsilon/T_e)$  - electron distribution function close to Maxwell, electron velocity limit -  $v_{lim} = (\varepsilon_{lim})^{1/2} = (3 \cdot T_e \cdot 2/m)^{1/2}$ ;  $S(\varepsilon) = S_{max} \cdot \varepsilon / \varepsilon_{max} \cdot e^{2(1-\sqrt{\varepsilon/\varepsilon_{max}})}$  - factor of secondary electron imission, where  $\varepsilon = (v_x^2 + v_y^2 + v_r^2) \cdot m/2$  - energy of electron falling to the DC surface,  $S_{max} = 2.5$  and  $\varepsilon_{max} = 500$  eV for material  $BN-SiO_2^1$ ; the stream of ions  $\langle V_{ir} \cdot n_i \rangle$  is certain on border of plasma and close to the wall layer. Radial component of ion velocity  $V_{ir}$  is determined by the next: chaotic energy of atom (100 ... 200 m/s) and the energy accumulated by an ion owing to ion acceleration by the radial component of an electric field in DC space outside of a layer; and also by the energy accumulated owing to acceleration in a preshift  $\sim (T_e/2)^{1/2}$  - Bohm velocity. In plasma before the preshift concentration of ions and electrons are equal  $n_e = n_i$ . Took into consideration, that ions are born in all DC space and move to a wall in increasing (from DC axis to DC walls) radial electric field  $E_r = 2...3$  V/mm of value. Being based on results of preliminary calculations, average speed of ions  $\langle V_{ir} \rangle$  in a stream directed to a wall on border of close to the wall layer is estimated as  $(1 ... 5) \cdot 1000$  m/s.

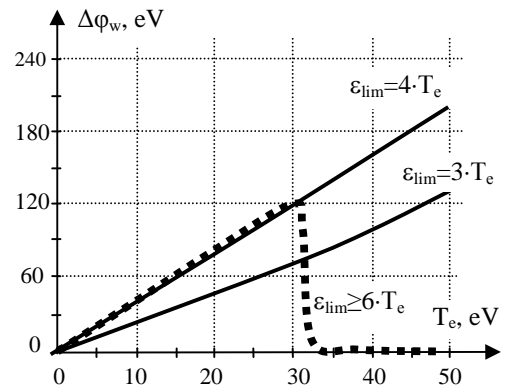


Figure 6. Dependence of potential drop  $\Delta\phi_w$  in close to the wall layer on electron temperature  $T_e$  for material  $BN-SiO_2$ . The maximal electron energy in EDFE does not surpass  $\varepsilon_{lim}$ .

## V. DC plasma parameters calculation

The intensity of ion origin process  $Q_i$  (quantity of ions born per second per unit of volume) and average electron energy  $\varepsilon$  in a discharge interval was numerically calculated base by Monte-Carlo (M-C) method modeling. By modeling the forms of the curve of magnetic and electric field's distribution (Fig.1) were taken (base on experimental data) as typical for the HT, but the value of potential drop was calculated on 1D hydrodynamic model in section II. By plasma parameters calculation the value of a radial component of electric field  $E_r$  was varied. Calculation on M-C model was carried out with time step of integration  $dt=0.05/w$ , where  $w$  – electron cyclotron frequency. By calculation the HT thrust created by all ions born in DC and accelerated in ZA was determined in a test task in diapason from 4 up to 4.4 grams, when the experimental value is 4 gram. It was required six hours operation of the personal computer to reach satisfactory repeatability of results of calculation.

Results of plasma parameters calculation in DC (look in Fig. 7) HT type M-70 (with external diameter  $D=70$  mm, width of the channel  $b_k=15$  mm, at a discharge voltage 280 V; an induction of a magnetic field 16 mTl; Xe mass flow rate through the anode block of 2.5 mg/s are shown in Tables 1-3. In tables:  $Q_i$  - quantity of ions born per second in cubic millimeter in space of ZI in DC;  $\varepsilon$  - average electron energy;  $E_r, E_x$  - radial and axial components of an electric field. By calculation of DC erosion it was accepted that electron temperature  $T_e=\varepsilon$ .

Similar calculations have been carried out when  $E_r=0$ .

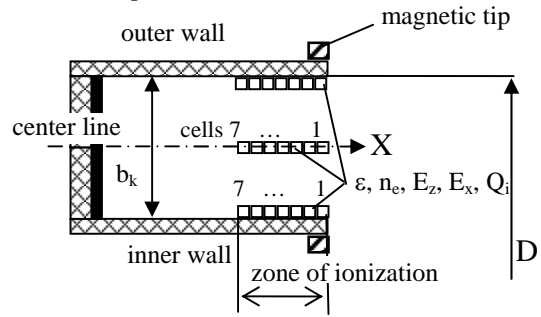


Figure 7. Numbering of cells in DC modeling area.

Table 1. Cells close to the auter wall (Fig. 7)

Distance from DC edge, mm	1	2	3	4	5	6	7
$E_x$ $E_r$ V/mm	27 2.4	27 3.5	14 4.0	6.8 4.1	2.9 4.1	0.8 4.2	0 4.2
$\varepsilon$ , eV	41	36	23	13	12	8	8
$Q_i, 10^{14}$ part/s/mm <sup>3</sup>	2.1	2.5	1.8	1.3	0.9	1.0	0.9

Table 2. Cells close to the inner wall (Fig. 7)

Distance from DC edge, mm	1	2	3	4	5	6	7
$E_x$ $E_r$ V/mm	27 2.5	27 3.6	14 4.1	6.8 4.2	2.9 4.2	0.8 4.3	0 4.3
$\varepsilon$ , eV	48	36	20	12	10	9	9
$Q_i, 10^{14}$ part/s/mm <sup>3</sup>	2.1	5.0	5.3	3.9	3.0	1.6	0.5

This artificial situation has been created to estimate a role of radial component of an electric field in DC space for strengthening DC wall erosion. Results of calculation of plasma parameters in DC are yield in Tables 4-6. It is necessary to notice that only 55 % of the Xe mass flow rate was ionized when  $E_r=0$  and the settlement value of thrust was 2.6 gram, whereas experimental value - 4 grams under condition of  $E_r \neq 0$ .

Table 3. Cells close to the center line (Fig. 7)

Distance from DC edge, Fig. 6	1	2	3	4	5	6	7
$E_x$ $E_r$ V/mm	29 0	29 0	14 0	6 0	1.6 0	0.2 0	0 0
$\varepsilon$ , eV	25	18	10	9	8	8	7
$Q_i, 10^{14}$ part/s/mm <sup>3</sup>	6.5	8.0	5.5	7.8	5.9	4.1	2.2



**Table 4.** Cells close to the outer wall (Fig. 7)

Distance from DC edge, mm	1	2	3	4	5	6	7
$E_x$ $E_r$ V/mm	29 0.1	29 0.1	14 0.1	6 0.1	1.8 0.1	0.1 0.1	0 0
$\varepsilon$ , eV	67	36	20	8	6	6	6
$Q_i$ , $10^{14}$ part/s/mm <sup>3</sup>	1.0	0.75	0.93	1.4	1.4	1.2	0.46

**Table 5.** Cells close to the inner wall (Fig. 7)

Distance from DC edge, mm	1	2	3	4	5	6	7
$E_x$ $E_r$ V/mm	27 0.1	27 0.1	14 0.1	6.8 0.1	2.9 0.1	0.3 0.1	0 0
$\varepsilon$ , eV	80	48	18	10	10	10	10
$Q_i$ , $10^{14}$ part/s/mm <sup>3</sup>	0.6	0.9	0.79	0.68	0.68	0.68	0.62

## VI. DC erosion profile calculation

It is known that the DC material sputtering yield strongly depends on surface temperature. Therefore for calculation of DC wall erosion it was calculated temperature distribution along DC working surface on the basis of balance of energy stream which is brought with particles from plasma to the DC surface, and which is radiated from this surface in outer space. By calculation of radiation of a surface with square  $S$  at temperature  $T_s$  on well-known Stefan-Boltzmann's relation for a grey body

$$N_{rad} = S \cdot \varepsilon \cdot T_s^4 \cdot \sigma$$

Factors  $\varepsilon=0.5$  and  $\sigma=5.6 \cdot 10^{-8} \text{ W}/(\text{m}^2 \cdot \text{K}^4)$  were used. To calculate temperature  $T_b$  of a surface, which does not contact to plasma, transfer of heat  $N_{con}$  to this surface from a wall contacting to plasma in view of factor of heat conductivity of DC material  $\lambda=0.44 \text{ W}/(\text{K} \cdot \text{m})$  is considered. The scheme of thermal streams is shown in Fig. 8. We

used the following equation to determine of an energy stream  $N_e$ , which is bring by electrons to DC surface, considering that electron with temperature  $T_e$  and a charge  $q$  overcome retarding potential  $\Delta\phi_w$  of close to the wall layer

$$N_e = n_e \cdot \exp(-\Delta\phi_w/T_e) \cdot (T_e \cdot 2 \cdot q/\pi/m_e)^{1/2}$$

At the DC input this stream brings  $\approx 0.1 \text{ W}$  of energy on  $1 \text{ mm}^2$ . Dependence of potential drop  $\Delta\phi_w$  on electron temperature has been determined early (Fig. 6.) Analyzing value of energy stream to a DC wall it is possible to results that more than 90 % of energy bring to a DC surface by electrons.

By calculations of DC erosion process movement of ions was modeled, considering: 1) that initial ion velocity is equal to velocity of atoms, which are distributed on Maxwell function; 2) data on  $Q_i$  (in Tables 1-6) – quantity of ions born per second in  $1 \text{ mm}^3$  in ZI of DC. Distribution of potential  $\phi(r)$  lengthways close to the wall layer (perpendicular to DC surface) was determined on the basis of Poisson equation. The ion trajectory in view of potential distribution  $\phi(r)$  in close to the wall layer was calculated.

Dependence of factor  $Y$  of DC material sputtering yield

9

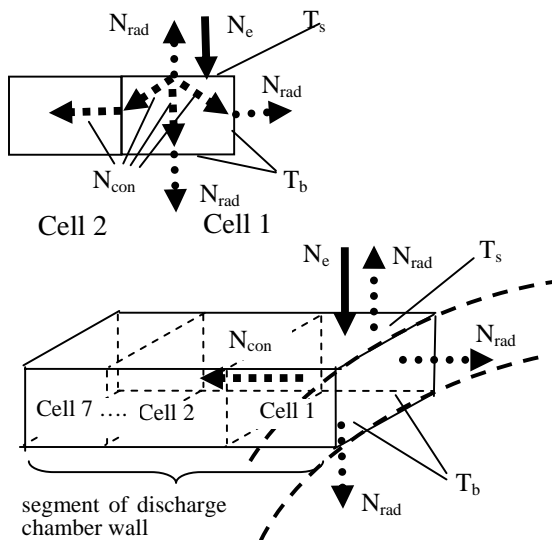


Figure 8. Heat balance through borders of cells allocated in DC body.

on a corner of Xe ion falling to DC surface and on Xe ion energy is considered<sup>2</sup> (look in Fig. 9 and 10). By calculation the value of a radial component of electric field  $E_r$  outside of close to the wall layer was varied. It was taking into account that in process of DC destruction (as width of the DC channel increase) intensity of an ion birth  $Q_i$  decreases in again appeared areas of the channel (removed from an average line in a radial direction) because of decreasing of neutral particles concentration in these areas.

Outcome of calculations for variants (when radial a component of electric field  $E_r$  it is not equal to zero and when  $E_r=0$ ) are resulted in a Fig. 11 and 12 where the calculated temperature  $T_s$  of DC surface also is specified.

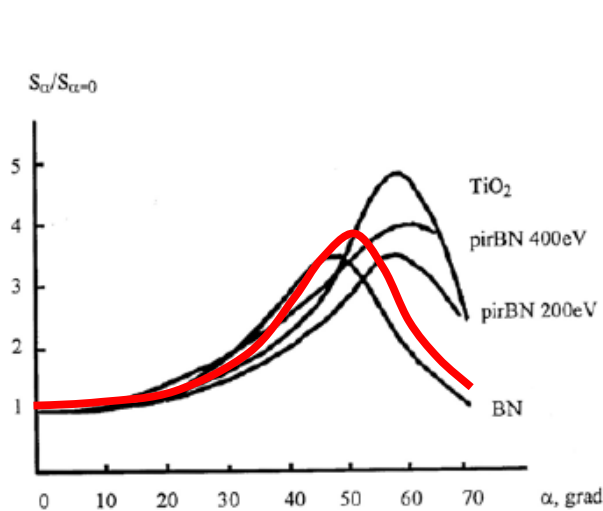


Figure 9. Dependence of DC material sputtering yield<sup>2</sup> on a corner of Xe ion falling to DC surface. Red curve - was used for calculations.

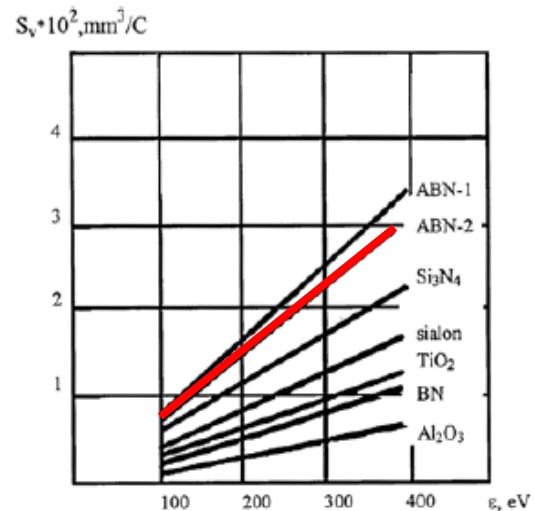


Figure 10. Dependence of DC material sputtering yield<sup>2</sup> on Xe ion energy. Red curve - was used for calculations.

## VII. Discussion and Conclusion

Life-time of HT M-70 type has been estimated in design bureau "Fakel" by 3500 hours, when thickness of DC wall is 3 mm. Our calculations of DC erosion (Fig. 11 and 12) show that rate of erosion is approximately 1.5 ... 2 times surpasses the erosion rate, which is supposed by manufacturer. The most probable direct reason of a deviation of our results of calculations (it is specified above) consists that the DC surface temperature has been overestimated. It has occurred as result of limitation of electron distribution function energy range by value of  $3T_e$ .

To explain experimental data about existence of electrons with temperature 40 eV and more it has been assumed that electron energy is limited by value of  $3T_e$ . Then existence of close to the wall layer with potential drop (not zero) is possible at electron temperatures more than 30 eV. This layer prevents an unlimited electron stream to a DC wall and cooling of electrons. As a result of calculations it has appeared that electron stream to a DC wall with concentration about  $10^{17} \text{ m}^{-3}$  in a zone of ionization (when electrons overcome the retarding potential drop in close to a DC wall layer and interact with a wall owing to what electrons move to the anode) in some times surpasses value of an axial electron current in DC (nearly 1 A). Thus, we have received inconsistent results: electron current to a DC wall considerably exceeds an axial electron current. The most probable reason of the overestimated value of an electron current to a DC wall consist in error of potential drop in close to a DC wall layer determining. It is the consequence of that electron energy was limited by value of  $3T_e$ . To correct calculation it is necessary to increase electron energy limit of distribution function up to  $4T_e$  ...  $5T_e$ . Then also would exist potential drop in close to the wall layer at  $T_e > 30 \text{ eV}$  and more. Then the electron current to DC surface would be in some times less. And, as consequence, DC surface temperature, which strongly influences DC sputtering yield, would be less.

Operation mode when  $E_r \rightarrow 0$  is artificially created for calculation of DC erosion. It has enabled to examine a hypothetical situation and to analyze whether costs aspires to create HT designs, in which  $E_r \rightarrow 0$ . Results of calculations show that radial component of an electric field considerably reduces electron stream to a DC wall. It limits DC surface temperature and reduces erosion rate. When  $E_r \rightarrow 0$  the big stream of electrons to a DC wall surface leads to heating of a DC wall and to cooling of electrons that in turn reduces intensity of a birth of ions and reduces thrust of HT.

Being based on results of calculations, we can summarize the basic features of discharge chamber erosion: the basic role in formation of the directed stream of ions to ceramic walls of chamber plays a radial component of an electric field, especially in the field of where a longitudinal component is small; the basic role in increasing of energy of an ions, which bombard the chamber walls, plays close to the wall potential drop; mainly due to electrons heating of the chamber walls that conducts to strengthening of erosion is going.

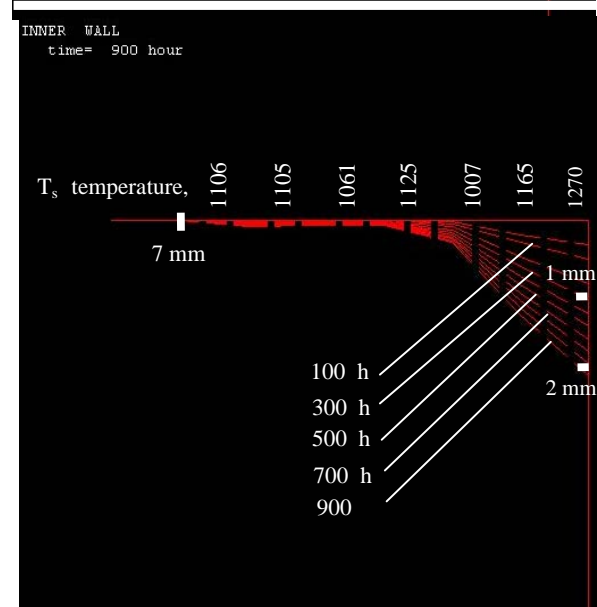
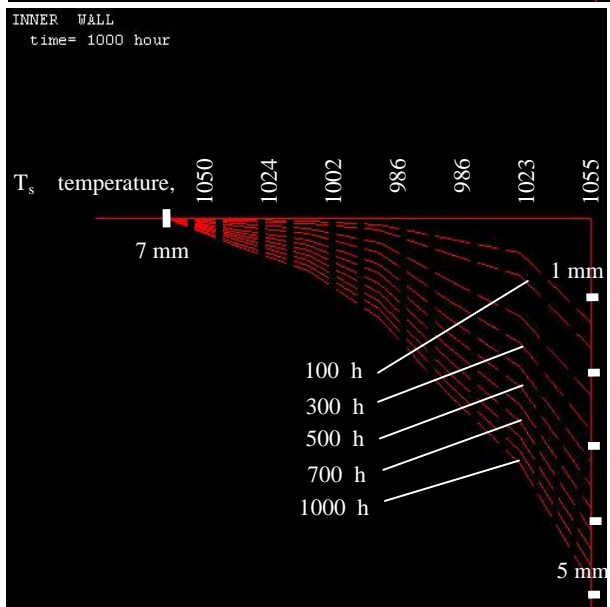
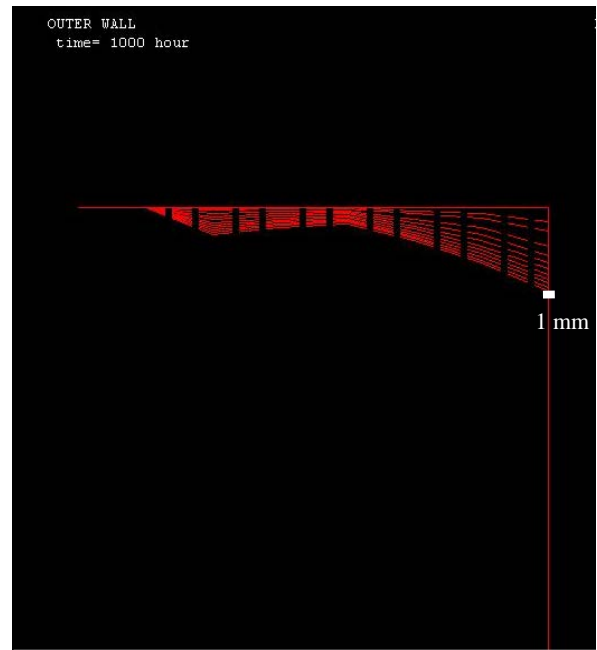
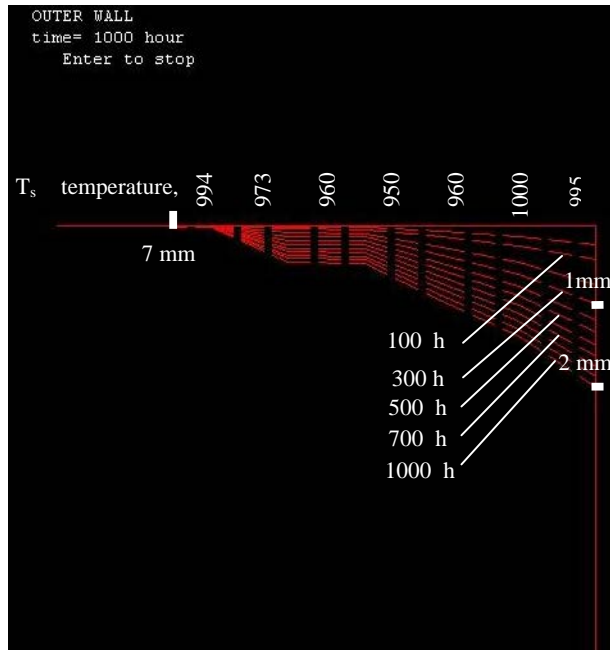


Figure 11. Distortion of the wall of HT M-70. DC surface temperature  $T_s$ . Radial component of electric field  $E_r \neq 0$ . Thrust was calculated as 4.2 grams.

Figure 12. Distortion of the wall of HT M-70. DC surface temperature  $T_s$ . Radial component of electric field  $E_r = 0$ . Thrust was calculated as 2.6 grams.

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